FAIRCHILD

SEMICONDUCTOR®

BC63916

Switching and Amplifier Applications



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

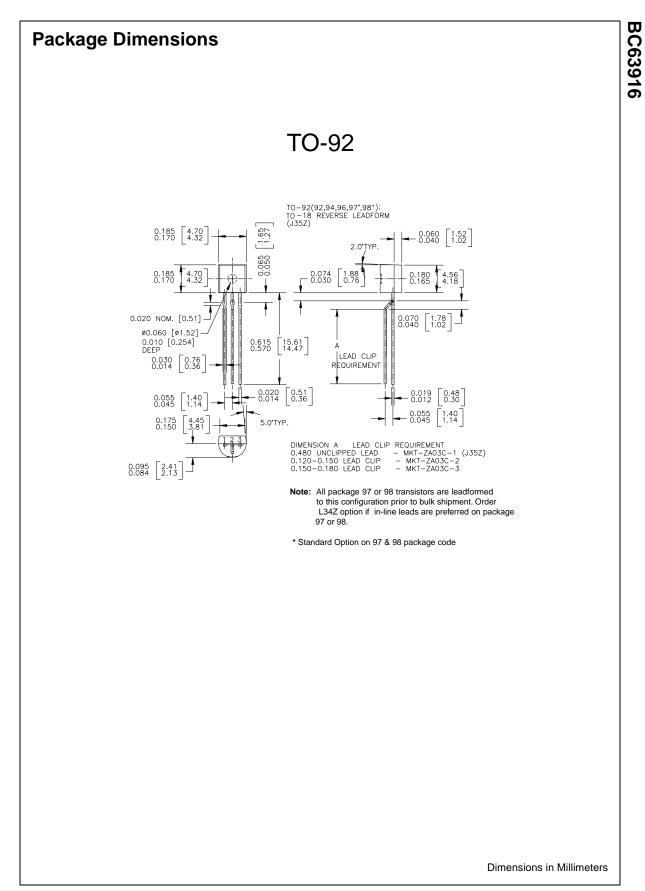
Parameter	Value	Units
Collector-Emitter Voltage at R _{BE} =1KΩ	100	V
Collector-Emitter Voltage	100	V
Collector-Emitter Voltage	80	V
Emitter-Base Voltage	5	V
Collector Current	1	А
Collector Power Dissipation	1	W
Operating and Storage Junction Temperature Range	-55 ~ 150	°C
	Collector-Emitter Voltage at R _{BE} =1KΩ Collector-Emitter Voltage Collector-Emitter Voltage Emitter-Base Voltage Collector Current Collector Power Dissipation	Collector-Emitter Voltage at R _{BE} =1KΩ 100 Collector-Emitter Voltage 100 Collector-Emitter Voltage 80 Emitter-Base Voltage 5 Collector Current 1 Collector Power Dissipation 1

Electrical Characteristics $T_a=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \mu {\rm A}, I_{\rm E} = 0$	100			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 10 {\rm mA}, I_{\rm B} = 0$	80			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \mu A, I_{\rm C} = 0$	5.0			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 30V, I_E = 0$			100	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			10	μΑ
h _{FE1} h _{FE2} h _{FE3}	DC Current Gain	$V_{CE} = 2V, I_C = 5mA$ $V_{CE} = 2V, I_C = 150mA$ $V_{CE} = 2V, I_C = 500mA$	25 100 25		250	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 500mA, I _B = 50mA			0.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 2V, I_{C} = 500 \text{mA}$			1	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 5V, I_C = 10mA,$ f = 50MHz		100		MHz

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